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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/934,334	08/21/2001	Paul R. Berger	3531-0103P	8252
2292	7590 01/26/2005		EXAMINER	
BIRCH STEWART KOLASCH & BIRCH PO BOX 747			KANG, DONGHEE	
FALLS CHURCH, VA 22040-0747			ART UNIT	PAPER NUMBER
	•		2811	

DATE MAILED: 01/26/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

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		Application No.	Applicant(s)	
		09/934,334	BERGER ET AL.	
	Office Action Summary	Examiner	Art Unit	
		Donghee Kang	2811	
Period fo	The MAILING DATE of this communication Reply	ion appears on the cover sheet w	vith the correspondence address	•
A SH THE - Exte after - If the - If NO - Failu Any	ORTENED STATUTORY PERIOD FOR MAILING DATE OF THIS COMMUNICAT nsions of time may be available under the provisions of 37 SIX (6) MONTHS from the mailing date of this communicate period for reply specified above is less than thirty (30) day to period for reply is specified above, the maximum statutor irre to reply within the set or extended period for reply will, it reply received by the Office later than three months after the patent term adjustment. See 37 CFR 1.704(b).	FION.  CFR 1.136(a). In no event, however, may a stion.  ys, a reply within the statutory minimum of the period will apply and will expire SIX (6) MC by statute, cause the application to become the period will apply and will expire SIX (6).	reply be timely filed irty (30) days will be considered timely. NTHS from the mailing date of this communica ABANDONED (35 U.S.C. § 133).	tion.
Status				
• —	Responsive to communication(s) filed on This action is <b>FINAL</b> . 2b) Since this application is in condition for a closed in accordance with the practice of	This action is non-final.  allowance except for formal ma	•	is
Disposit	ion of Claims			
5)□ 6)⊠ 7)⊠	Claim(s) <u>54-85</u> is/are pending in the app 4a) Of the above claim(s) <u>56,57,67,68,79</u> Claim(s) is/are allowed. Claim(s) <u>54-55, 58-66, 69-70, 72, &amp; 74-68</u> Claim(s) is/are objected to. Claim(s) are subject to restriction	<u>1,73 and 83-85</u> is/are withdrawi <u>82</u> is/are rejected.	n from consideration.	
Applicat	ion Papers			
10)□	The specification is objected to by the Extra The drawing(s) filed on is/are: a) Applicant may not request that any objection Replacement drawing sheet(s) including the The oath or declaration is objected to by	☐ accepted or b)☐ objected to to the drawing(s) be held in abeys correction is required if the drawin	ance. See 37 CFR 1.85(a). g(s) is objected to. See 37 CFR 1.12	
Priority	under 35 U.S.C. § 119			
a)	Acknowledgment is made of a claim for the All b) Some * c) None of:  1. Certified copies of the priority doces.  2. Certified copies of the priority doces.  3. Copies of the certified copies of the application from the International See the attached detailed Office action for	cuments have been received. cuments have been received in he priority documents have bee Bureau (PCT Rule 17.2(a)).	Application No n received in this National Stage	
2) Noti	nt(s) ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO- rmation Disclosure Statement(s) (PTO-1449 or PTO- er No(s)/Mail Date 8-21-01.	948) Paper N	v Summary (PTO-413) o(s)/Mail Date f Informal Patent Application (PTO-152) 	

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### **DETAILED ACTION**

### Claim Rejections - 35 USC § 112

1. The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

2. Claims **54-55 & 58-82** are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Re claims **54-55 & 74**, the phrase "the bottom injector and the top injector layers forming a p-n junction" is unclear how to form the p-n junction between the bottom injector and top injector layers because the top injector is separated by an barrier layer from the bottom injector.

Claims **58-73 & 75-82** are rejected because each includes the limitations of independent claims **54-55 & 74**.

The examiner interprets "a p-n junction" as a p-n injectors for further examination.

# Claim Rejections - 35 USC § 102

3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 4. Claims **54**, **58-60**, **& 62-63** are rejected under 35 U.S.C. 102(b) as being anticipated by Sweeny et al. (Mark Sweeny, "Resonant interband tunnel diodes", Appl. Phys. Lett., pp 546-548, 1989).

Re claim 54, Sweeny et al. teach a method of fabricating an interband tunnel diode, the method comprising the steps of (Fig.1):

layering a n-type bottom injector (I); layering a p-type top injector (IV) adjacent to the bottom injector; and layering a barrier material between the bottom injector and top injector. See pages 546.

Re claims 58 & 59, Sweeny et al. teach the layers in the interband tunnel diode are grown epitaxially, wherein the layers are semiconductor..

Re claim 60, Sweeny et al. teach the epitaxial layers comprised of a group IV alloy.

Re claims 62-63, Sweeny et al. teach the layers are grown in a molecular bean epitaxial growth system or chemical vapor deposition growth system.

## Response to Arguments

5. Applicant's arguments filed 11-08-04 have been fully considered but they are not persuasive.

Applicant argues that the bottom injection layer, the top injection layer, and said material form a p-n junction. This is not convincing. The "P-N junction" is well known term in the art that is formed by brining the n-type material into contact with the p-type material. The elected embodiment 1 as described in Figs.1 & 4 shows there is no n-type material being in contact with the p-type material to form p-n junction.

6. The lack of an art rejection with this office action is not an indication of allowable subject matter (i.e., even though the claims are rewritten or amended to overcome the

rejection under U.S.C. 112 as discussed above). The disclosure/claimed language is such that it is impractical to conduct a reasonable search of the prior art by the Examiner.

### Conclusion

7. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

8. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Donghee Kang whose telephone number is 571-272-1656. The examiner can normally be reached on Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie C. Lee can be reached on 571-272-1732. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Donghee Kang
Primary Examiner
Art Unit 2811

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